TOSHIBA Field Effect Transistor Silicon P Channel MOS Type

2SJ313

Audio Frequency Power Amplifier Application

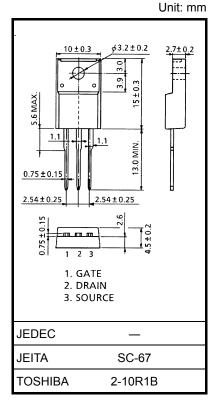
• High breakdown voltage: $V_{DSS} = -180 \text{ V}$

 $\bullet~$ High forward transfer admittance: $|\,Y_{fs}\,|\,$ = 0.7 S (typ.)

• Complementary to 2SK2013

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V_{DSS}	-180	٧
Gate-source voltage	V_{GSS}	±20	٧
Drain current (Note 1)	ΙD	-1	Α
Power dissipation (Tc = 25°C)	P_{D}	25	W
Channel temperature	T _{ch}	150	°C
Storage temperature range	T _{stg}	-55~150	°C



Weight: 1.9 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	V _{DS} = 0, V _{GS} = ±20 V	_	_	±100	nA
Drain-source breakdown voltage	V (BR) DSS	I _D = -10 mA, V _{GS} = 0	-180	_	_	V
Gate-source cut-off voltage (Note 2)	V _{GS} (OFF)	$V_{DS} = -10 \text{ V}, I_D = -10 \text{ mA}$	-0.8	_	-2.8	V
Drain-source saturation voltage	V _{DS} (ON)	$I_D = -0.6 \text{ A}, V_{GS} = -10 \text{ V}$	_	-1.2	-3.0	V
Forward transfer admittance	Y _{fs}	$V_{DS} = -10 \text{ V}, I_D = -0.3 \text{ A}$	_	0.7	_	S
Input capacitance	C _{iss}		_	210	_	
Output capacitance	Coss	$V_{DS} = -10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	90	_	pF
Reverse transfer capacitance	C _{rss}		_	45	_	

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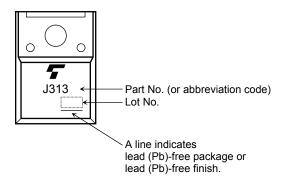
Note 1: Ensure that the channel temperature does not exceed 150°C.

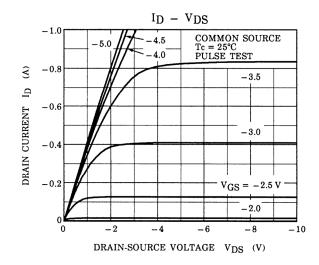
Note 2: $V_{GS (OFF)}$ Classification O: $-0.8 \sim -1.6$, Y: $-1.4 \sim -2.8$

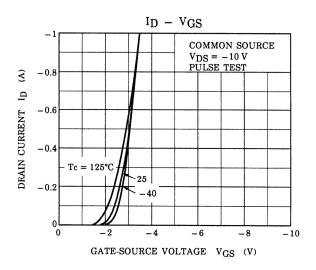
This transistor is the electrostatic-sensitive device.

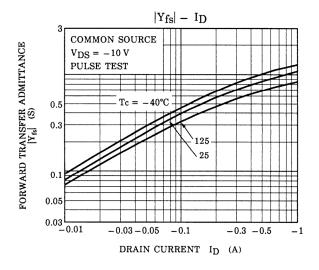
Please handle with caution.

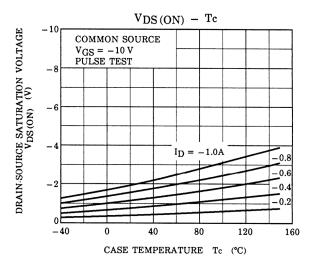
Marking

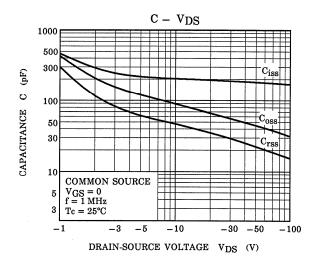


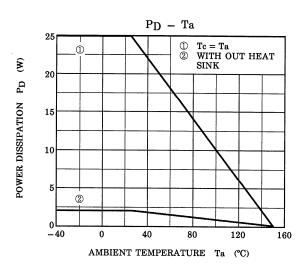


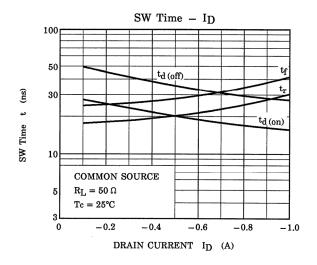


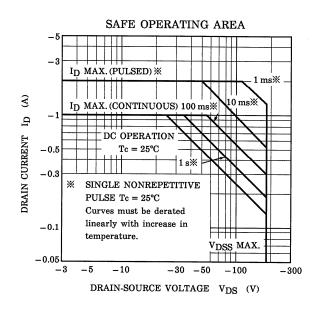




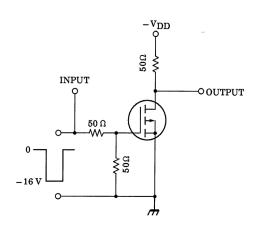




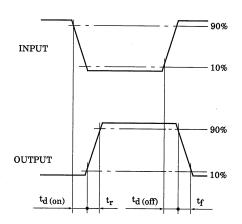




Test Circuit



Waveforms



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